

## 1.4W Mono Audio Low-Voltage Audio Power Amplifier

### Features

- Operating Voltage: 2.5V-5.5V
- Supply Current
  - $I_{DD}=1.5\text{mA}$  at  $V_{DD}=5\text{V}$
  - $I_{DD}=1.2\text{mA}$  at  $V_{DD}=3.6\text{V}$
  - $I_{DD}=1\text{mA}$  at  $V_{DD}=2.5\text{V}$
- Low Shutdown Current
  - $I_{DD}=0.5\mu\text{A}$  at  $V_{DD}=5\text{V}$
- Low Distortion
  - 0.85W, at  $V_{DD}=5\text{V}$ ,  $R_L=8\Omega$  THD+N=0.05%
  - 0.43W, at  $V_{DD}=3.6\text{V}$ ,  $R_L=8\Omega$  THD+N=0.05%
  - 0.6W, at  $V_{DD}=3.6\text{V}$ ,  $R_L=4\Omega$  THD+N=0.09%
  - 0.2W, at  $V_{DD}=2.5\text{V}$ ,  $R_L=8\Omega$  THD+N=0.09%
  - 0.26W, at  $V_{DD}=2.5\text{V}$ ,  $R_L=4\Omega$  THD+N=0.1%
- Output Power
  - at 1% THD+N
    - 1.2W, at  $V_{DD}=5\text{V}$ ,  $R_L=8\Omega$
    - 0.6W, at  $V_{DD}=3.6\text{V}$ ,  $R_L=8\Omega$
    - 0.82W, at  $V_{DD}=3.6\text{V}$ ,  $R_L=4\Omega$
    - 0.27W, at  $V_{DD}=2.5\text{V}$ ,  $R_L=8\Omega$
    - 0.36W, at  $V_{DD}=2.5\text{V}$ ,  $R_L=4\Omega$
  - at 10% THD+N
    - 1.4W, at  $V_{DD}=5\text{V}$ ,  $R_L=8\Omega$
    - 0.75W, at  $V_{DD}=3.6\text{V}$ ,  $R_L=8\Omega$
    - 1.05W, at  $V_{DD}=3.6\text{V}$ ,  $R_L=4\Omega$
    - 0.35W, at  $V_{DD}=2.5\text{V}$ ,  $R_L=8\Omega$
    - 0.46W, at  $V_{DD}=2.5\text{V}$ ,  $R_L=4\Omega$
- Depop Circuitry Integrated
- Thermal Shutdown Protection and Over Current Protection Circuitry

- High supply voltage ripple rejection
- Surface-Mount Packaging
  - 9 bump WLCSP
- Lead Free Available (RoHS Compliant)

### General Description

The APA0712 is a mono BTL audio power amplifier developed especially for low-voltage applications where internal speakers are required. Operating with a 5V supply, the APA0712 can deliver 1.4W of continuous power into a BTL 8Ω load at 10% THD+N throughout voice band frequencies. Although this device is characterized out to 20kHz, its operation is optimized for narrow band applications such as wireless communications. The BTL configuration eliminates the need for external coupling capacitors on the output in most applications, which is particularly important for small battery-powered equipment. This device features a shutdown mode for power-sensitive applications with special depop circuitry to eliminate speaker noise when exiting shutdown mode. The APA0712 is available in 9 bumps WLCSP.

### Applications

- Mobil Phones
- PDAs
- Digital Camera
- Portable Electronic Devices

ANPEC reserves the right to make changes to improve reliability or manufacturability without notice, and advise customers to obtain the latest version of relevant information to verify before placing orders.



## Absolute Maximum Ratings

(Over operating free-air temperature range unless otherwise noted.)

| Symbol                  | Parameter                            | Rating             | Unit |
|-------------------------|--------------------------------------|--------------------|------|
| $V_{DD}$                | Supply Voltage                       | -0.3 to 6          | V    |
| $V_{IN}, \overline{SD}$ | Input Voltage                        | -0.3 to 6          | V    |
| $T_A$                   | Operating Junction Temperature Range | -40 to 85          | °C   |
| $T_J$                   | Maximum Junction Temperature         | 150                | °C   |
| $T_{STG}$               | Storage Temperature Range            | -65 to +150        | °C   |
| $T_{SDR}$               | Lead Soldering Temperature Range     | 260, 10 seconds    | °C   |
| $P_D$                   | Power Dissipation                    | Internally Limited | W    |

Notes : Absolute Maximum Ratings are those values beyond which the life of a device may be impaired. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## Thermal Characteristics

| Symbol        | Parameter  | Value | Unit  |
|---------------|--|-------|-------|
| $\theta_{JA}$ | Thermal Resistance -Junction to Ambient<br>WLCSP-9 | 165   | °C /W |

## Recommended Operating Conditions

|  |                 | Min. | Max. | Unit |
|--|-----------------|------|------|------|
| Supply Voltage $V_{DD}$                |                 | 2.5  | 5.5  | V    |
| High level threshold voltage, $V_{IH}$ | $\overline{SD}$ | 2    |      | V    |
| Low level threshold voltage, $V_{IL}$  | $\overline{SD}$ |      | 0.8  | V    |

## Electrical Characteristics

$V_{DD}=5V, GND=0V, T_A=25\text{ }^\circ\text{C}$  (unless otherwise noted)

| Symbol  | Parameter                             | Test Condition  | Min. | Typ.         | Max. | Unit                |
|---|---------------------------------------|---|------|--------------|------|---------------------|
| $V_{DD}$  | Supply Voltage                        |   | 2.5  |              | 5.5  | V                   |
| $I_{DD}$  | Supply Current                        |   |      | 1.5          | 2.5  | mA                  |
| $I_{SD}$  | Shutdown Current                      | $\overline{SD} = 0V$  |      | 1            |      | $\mu\text{A}$       |
| $I_i$   | Input current                         | $\overline{SD}$   |      | 0.1          |      | $\mu\text{A}$       |
| <b><math>V_{DD}=5V, T_A=25\text{ }^\circ\text{C}</math></b>   |                                       |   |      |              |      |                     |
| $P_o$   | Output Power                          | THD+N = 1%, f = 1KHz<br>$R_L = 8\Omega$                                 | 1    | 1.1          |      | W                   |
|   |                                       | THD+N = 10%, f = 1KHz<br>$R_L = 8\Omega$                                |      | 1.4          |      |                     |
| THD+N   | Total Harmonic Distortion Pulse Noise | f = 1KHz<br>$P_o = 0.85W, R_L = 8\Omega$                                |      | 0.05         |      | %                   |
| PSRR  | Power Supply Rejection Ratio          | $C_B = 2.2\mu\text{F}, R_L = 8\Omega,$<br>f = 120Hz                     |      | 90           |      | dB                  |
| $V_{os}$  | Output Offset Voltage                 | $R_L = 8\Omega$   |      |              | 20   | mV                  |
| S/N   |                                       | With A-weighted Filter<br>$P_o = 0.85W, R_L = 8\Omega$                  |      | 99           |      | dB                  |
| $V_n$   | Noise Output Voltage                  | $C_B = 2.2\mu\text{F}$  |      | 20           |      | $\mu\text{V (rms)}$ |
| <b><math>V_{DD}=3.6V, T_A=25\text{ }^\circ\text{C}</math></b> |                                       |   |      |              |      |                     |
| $P_o$   | Output Power                          | THD+N = 1%, f = 1KHz<br>$R_L = 4\Omega$<br>$R_L = 8\Omega$              |      | 0.8<br>0.6   |      | W                   |
|   |                                       | THD+N = 10%, f = 1KHz<br>$R_L = 4\Omega$<br>$R_L = 8\Omega$             |      | 1<br>0.7     |      |                     |
| THD+N   | Total Harmonic Distortion Pulse Noise | f = 1KHz<br>$P_o = 0.6W, R_L = 4\Omega$<br>$P_o = 0.43W, R_L = 8\Omega$ |      | 0.09<br>0.05 |      | %                   |
| PSRR  | Power Supply Rejection Ratio          | $C_B = 1\mu\text{F}, R_L = 8\Omega,$<br>f = 120Hz                       |      | 80           |      | dB                  |
| $V_{os}$  | Output Offset Voltage                 | $R_L = 8\Omega$   |      |              | 20   | mV                  |
| S/N   |                                       | With A-weighted Filter<br>$P_o = 0.43W, R_L = 8\Omega,$                 |      | 96           |      | dB                  |
| $V_n$   | Noise Output Voltage                  | $C_B = 2.2\mu\text{F}$  |      | 20           |      | $\mu\text{V (rms)}$ |

## Electrical Characteristics (Cont.)

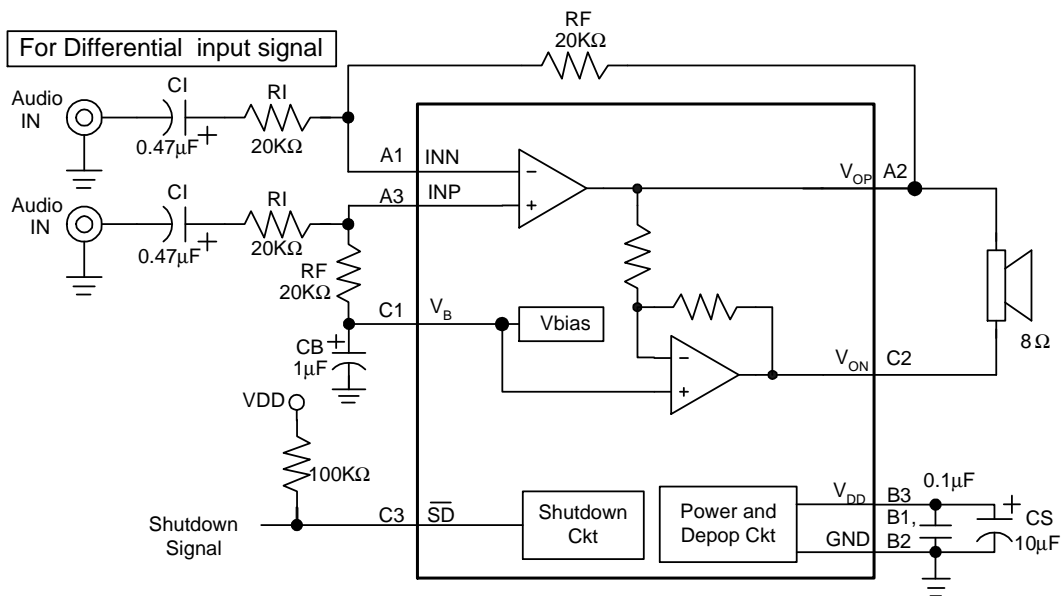
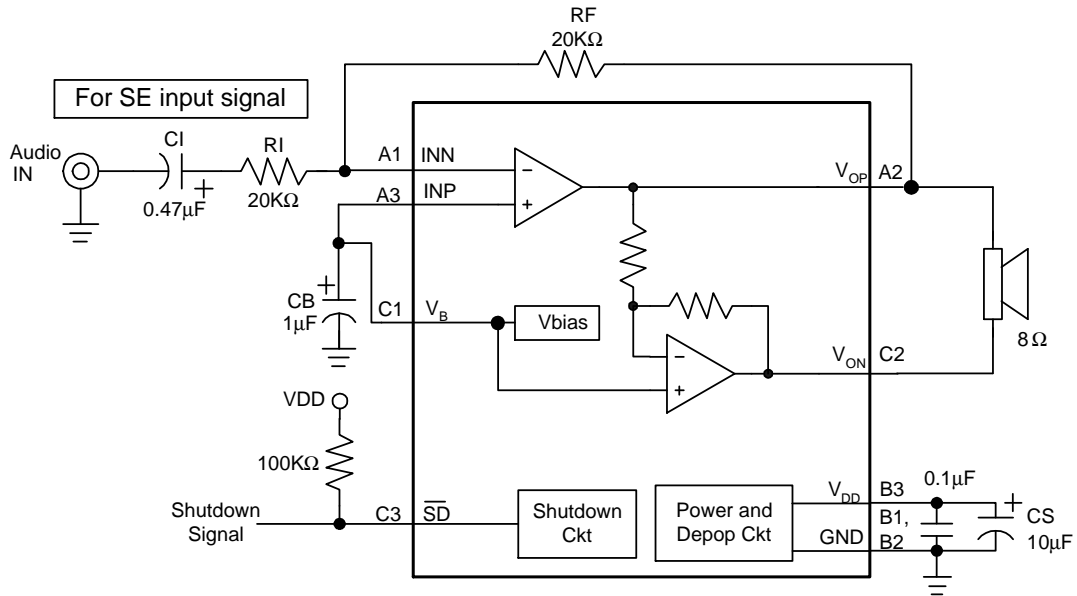
$V_{DD}=5V$ ,  $GND=0V$ ,  $T_A=25\text{ }^\circ\text{C}$  (unless otherwise noted)

| Symbol  | Parameter                             | Test Condition  | Min. | Typ.         | Max. | Unit             |
|---|---------------------------------------|---|------|--------------|------|------------------|
| <b><math>V_{DD}=2.5V, T_A=25\text{ }^\circ\text{C}</math></b> |                                       |   |      |              |      |                  |
| Po  | Output Power                          | THD+N = 1%, f = 1KHz<br>$R_L = 4\Omega$<br>$R_L = 8\Omega$              |      | 0.36<br>0.27 |      | W                |
|   |                                       | THD+N = 10%, f = 1KHz<br>$R_L = 4\Omega$<br>$R_L = 8\Omega$             |      | 0.46<br>0.34 |      |                  |
| THD+N   | Total Harmonic Distortion Pulse Noise | f = 1KHz<br>$P_O = 0.26W, R_L = 4\Omega$<br>$P_O = 0.2W, R_L = 8\Omega$ |      | 0.1<br>0.08  |      | %                |
| PSRR  | Power Supply Rejection Ratio          | $C_B = 2.2\mu F, R_L = 8\Omega$ ,<br>f = 120Hz                          |      | 58           |      | dB               |
| Vos   | Output Offset Voltage                 | $R_L = 4\Omega$   |      |              | 20   | mV               |
| S/N   |                                       | With A-weighted Filter<br>$P_O = 0.2W, R_L = 8\Omega$                   |      | 93           |      | dB               |
| Vn  | Noise Output Voltage                  | $C_B = 2.2\mu F$  |      | 20           |      | $\mu V$<br>(rms) |

## Pin Descriptions

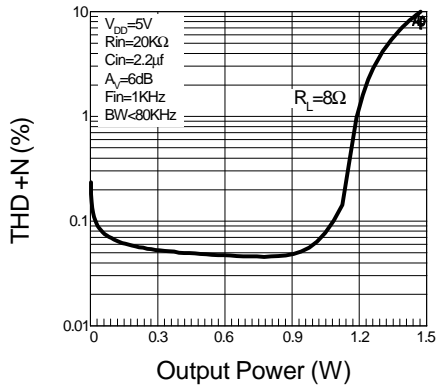
| Pin |                 | I/O | Function Description   |
|-----|-----------------|-----|--|
| NO. | Name            |     |  |
| A1  | INN             | I   | The inverting input of amplifier. INN is used as audio input terminal, typically.                  |
| A2  | $V_{OP}$        | O   | The positive output terminal of BTL amplifier.   |
| A3  | INP             | I   | The non-inverting input of amplifier. INP is tied to VB terminal for single-end (SE) input signal. |
| B1  | GND             | -   | Ground connection for circuitry.   |
| B2  | GND             | -   | Ground connection for circuitry.   |
| B3  | $V_{DD}$        | -   | Supply voltage input pin   |
| C1  | $V_B$           | -   | Bypass pin   |
| C2  | $V_{ON}$        | O   | The negative output terminal of BTL amplifier.   |
| C3  | $\overline{SD}$ | I   | Shutdown mode control signal input, place entire IC in shutdown mode when held low.                |

Typical Application Circuit

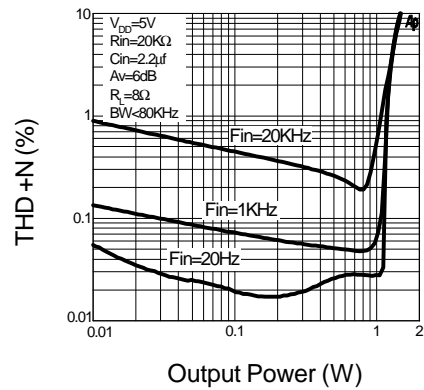


## Typical Operating Characteristics

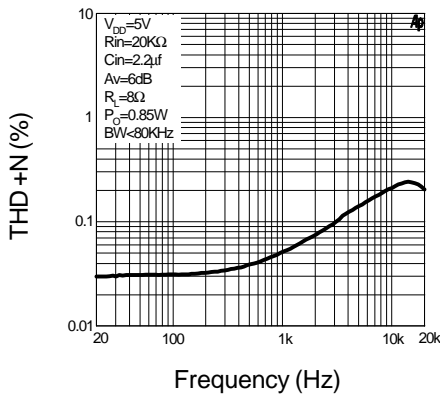
THD +N vs. Output Power



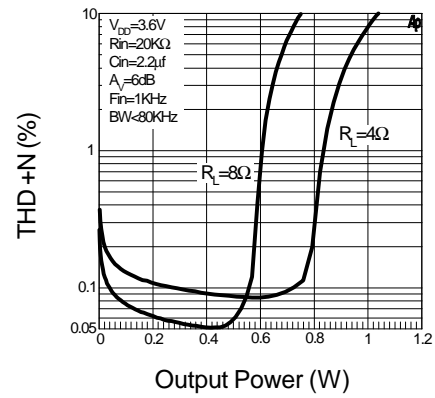
THD +N vs. Output Power



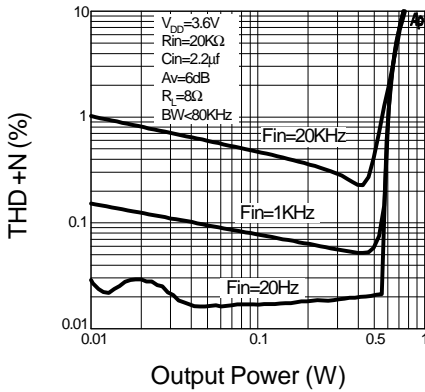
THD +N vs. Frequency



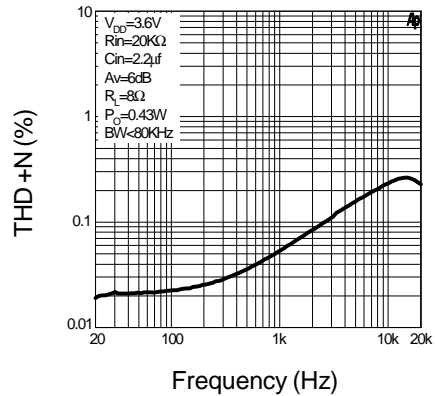
THD +N vs. Output Power



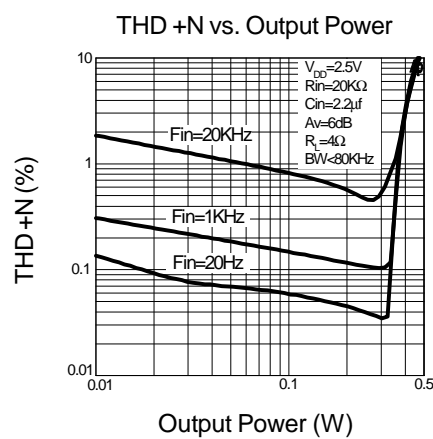
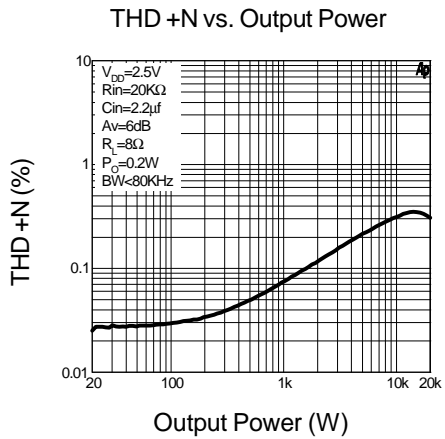
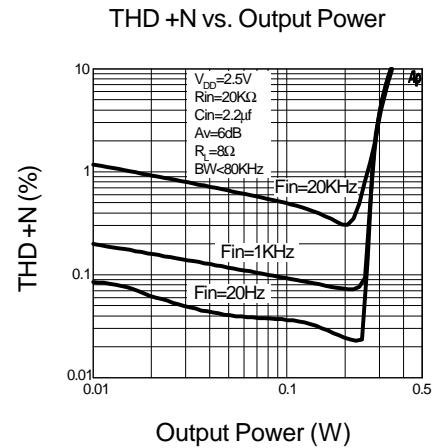
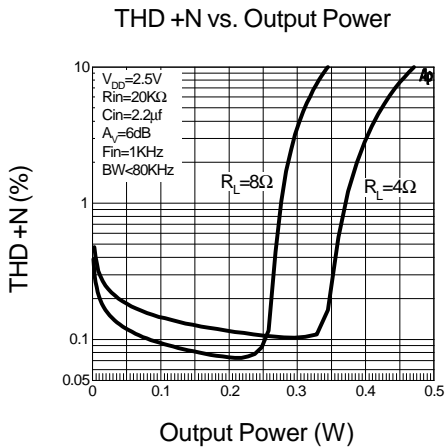
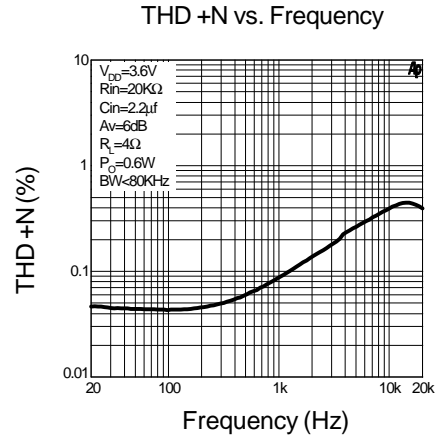
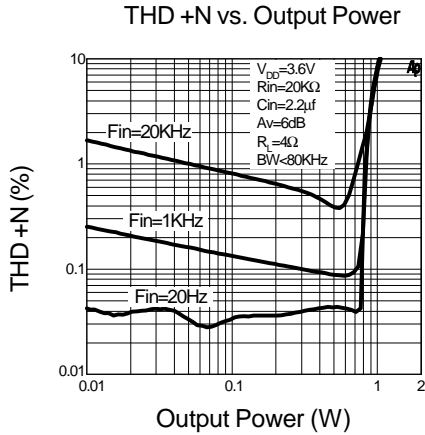
THD +N vs. Output Power



THD +N vs. Frequency



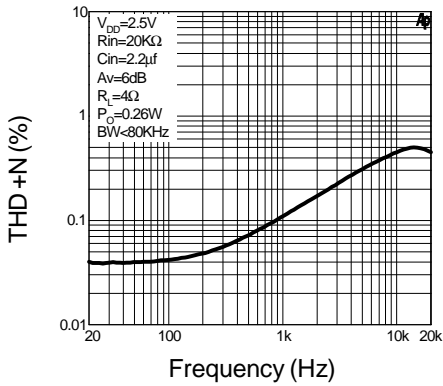
Typical Operating Characteristics (Cont.)



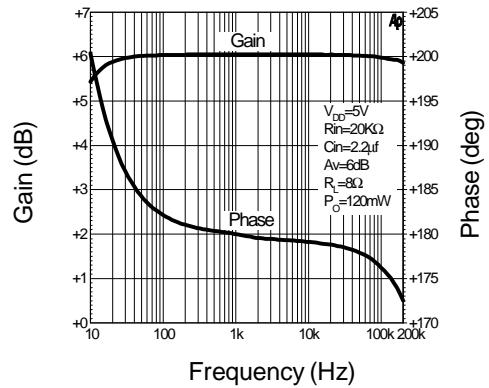


Typical Operating Characteristics (Cont.)

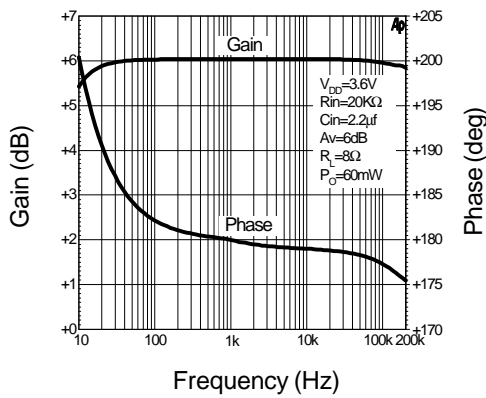
THD +N vs. Frequency



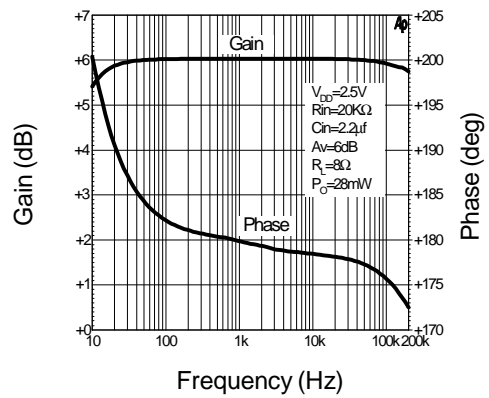
Frequency Response



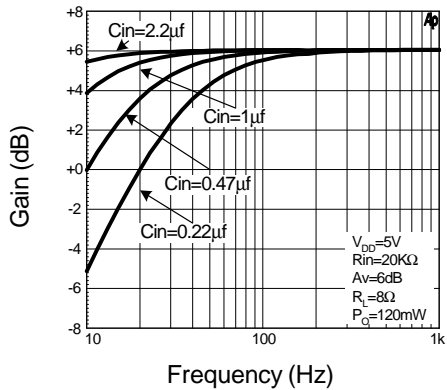
Frequency Response



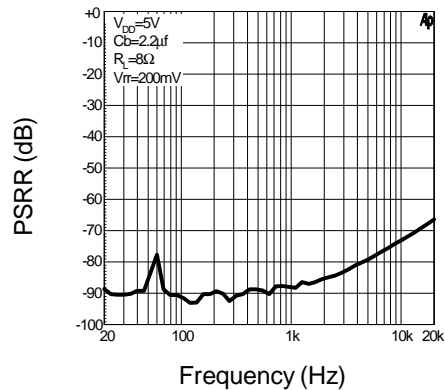
Frequency Response



THD +N vs. Output Power

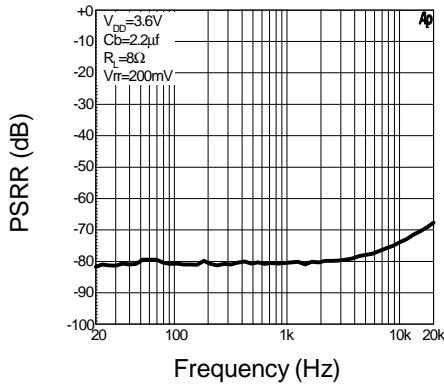


PSRR vs. Frequency

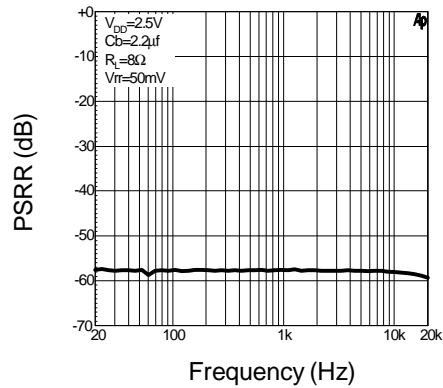


Typical Operating Characteristics (Cont.)

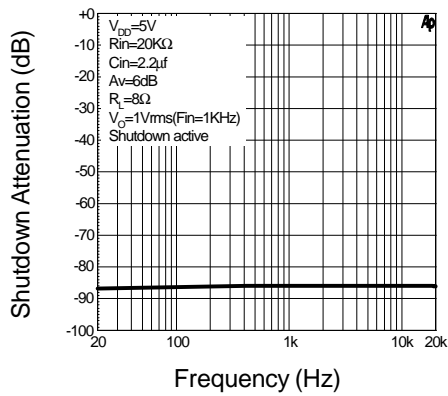
PSRR vs. Frequency



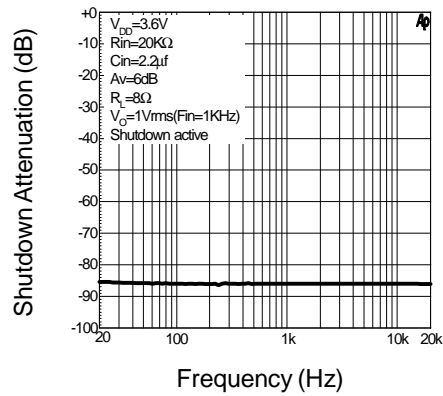
PSRR vs. Frequency



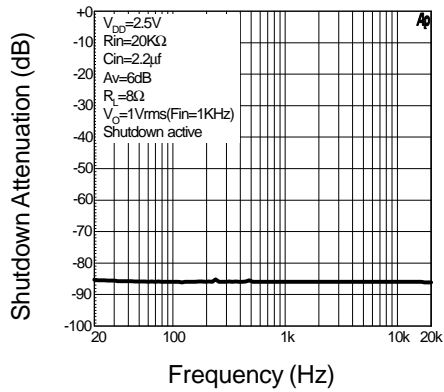
Shutdown Attenuation vs. Frequency



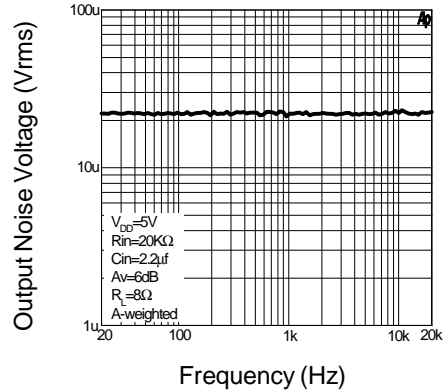
Shutdown Attenuation vs. Frequency



Shutdown Attenuation vs. Frequency

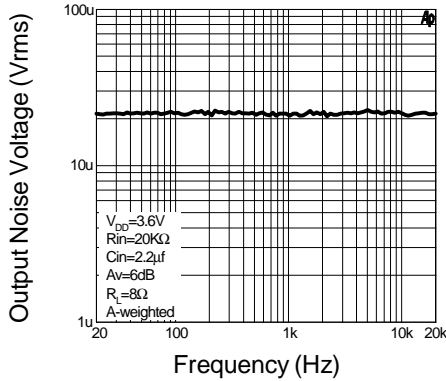


Output Noise Voltage vs. Frequency

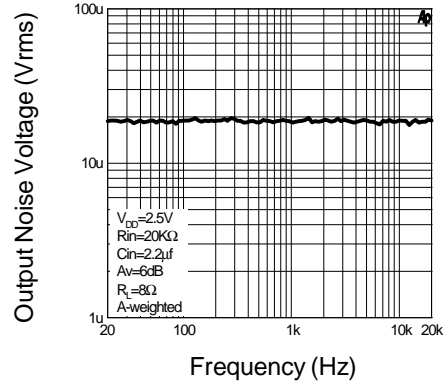


Typical Operating Characteristics (Cont.)

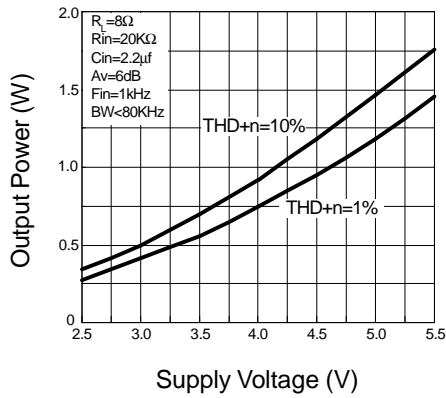
Output Noise Voltage vs. Frequency



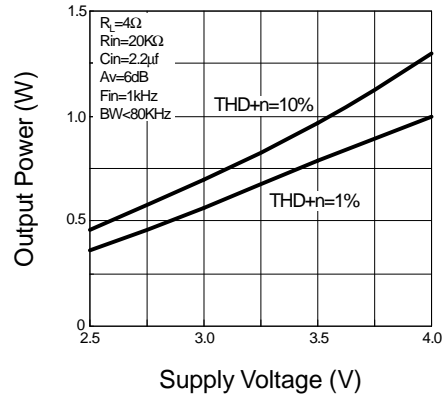
Output Noise Voltage vs. Frequency



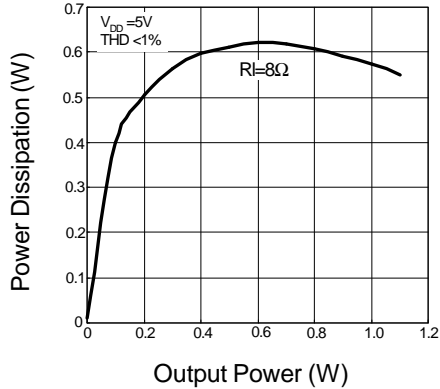
Output Power vs. Supply Voltage



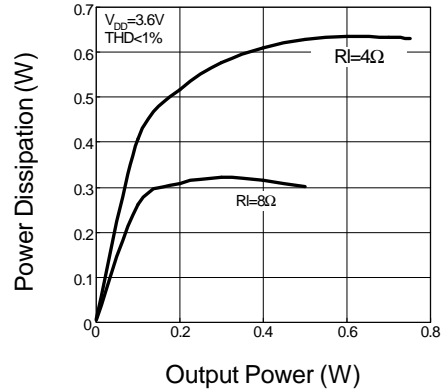
Output Power vs. Supply Voltage



Power Dissipation vs. Output Power

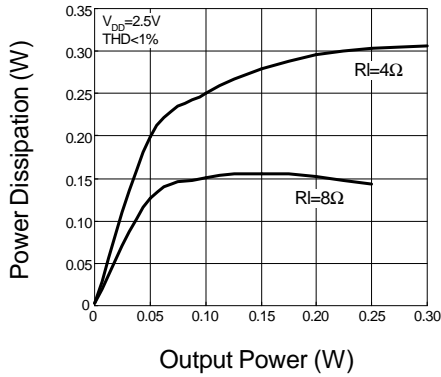


Power Dissipation vs. Output Power

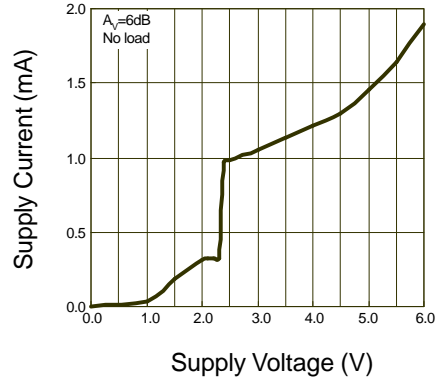


## Typical Operating Characteristics (Cont.)

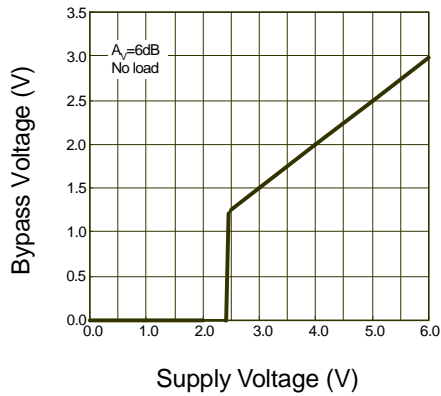
Power Dissipation vs. Output Power



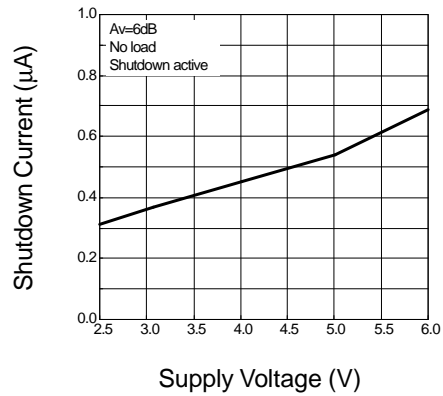
Supply Current vs. Supply Voltage



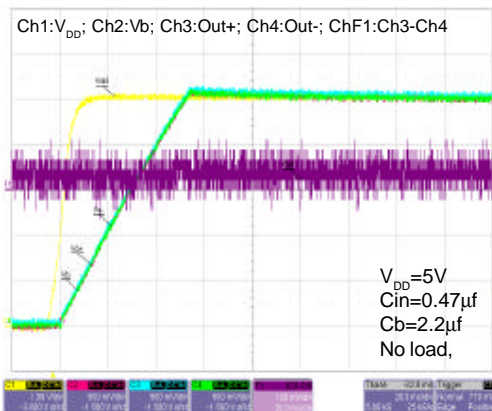
Bypass Voltage vs. Supply Voltage



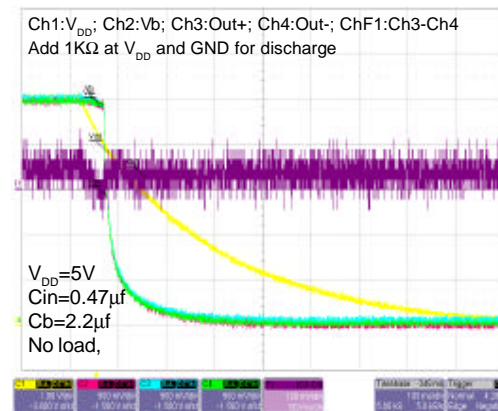
Shutdown Current vs. Supply Voltage



Power On Waveform



Power Off Waveform



## Application Descriptions

### BTL Operation

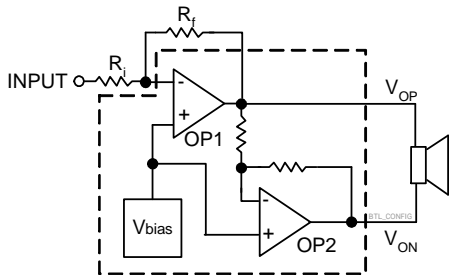


Figure1: APA0712 power amplifier internal configuration

The power amplifier OP1 gain is set by external gain setting, while the second amplifier OP2 is internally fixed in a unity-gain, inverting configuration. Figure 1 shows that the output of OP1 is connected to the input to OP2, which results in the output signals of with both amplifiers with identical in magnitude, but out of phase 180°. Consequently, the differential gain for each channel is 2X (Gain of SE mode).

By driving the load differentially through outputs  $V_{OP}$  and  $V_{ON}$ , an amplifier configuration commonly referred to as bridged mode is established. BTL mode operation is different from the classical single-ended SE amplifier configuration where one side of its load is connected to ground.

A BTL amplifier design has a few distinct advantages over the SE configuration, as it provides differential drive to the load, thus doubling the output swing for a specified supply voltage. Four times the output power is possible as compared to a SE amplifier under the same conditions.

ABTL configuration, such as the one used in APA0712, also creates a second advantage over SE amplifiers. Since the differential outputs,  $V_{OP}$ ,  $V_{ON}$  are biased at half supply, no need DC voltage exists across the load. This eliminates the need for an output coupling capacitor, which is required in a single supply, SE configuration.

### Input Resistance, $R_i$

The gain of the APA0712 is set by the external resistors ( $R_i$  and  $R_f$ ).

$$\text{BTL Gain} = -2 \times \frac{R_f}{R_i} \tag{1}$$

BTL mode operation brings the factor of 2 in the gain equation due to the inverting amplifier mirroring the voltage swing across the load. The input resistance will affect the low frequency performance of audio signal.

### Input Capacitor, $C_i$

In the typical application an input capacitor,  $C_i$ , is required to allow the amplifier to bias the input signal to the proper DC level for optimum operation. In this case,  $C_i$  and the minimum input impedance  $R_i$  from a high-pass filter with the corner frequency determined in the follow equation:

$$F_{C(\text{highpass})} = \frac{1}{2\pi R_i C_i} \tag{2}$$

The value of  $C_i$  is important to consider as it directly affects the low frequency performance of the circuit. Consider the example where  $R_i$  is 20kΩ and the specification calls for a flat bass response down to 40Hz. Equation is reconfigured as follow:

$$C_i = \frac{1}{2\pi R_i F_c} \tag{3}$$

Consider to input resistance variation, the  $C_i$  is 0.2μF so one would likely choose a value in the range of 0.22μF to 1.0μF. A further consideration for this capacitor is the leakage path from the input source through the input network ( $R_i + R_f$ ,  $C_i$ ) to the load.

This leakage current creates a DC offset voltage at the input to the amplifier that reduces useful headroom, especially in high gain applications. For this reason a low-leakage tantalum or ceramic capacitor is the best choice. When polarized capacitors are used, the positive side of the capacitor should face the amplifier input in most applications as the DC level there is held

## Application Descriptions (Cont.)

### Input Capacitor, $C_i$ (Cont.)

at  $V_{DD}/2$ , which is likely higher than the source DC level. Please note that it is important to confirm the capacitor polarity in the application.

### Effective Bypass Capacitor, $C_b$

As other power amplifiers, proper supply bypassing is critical for low noise performance and high power supply rejection.

The capacitors located on the bypass and power supply pins should be as close to the device as possible. The effect of a larger half supply bypass capacitor will improve PSRR due to increased half-supply stability. Typical applications employ a 5V regulator with 1.0 $\mu$ F and a 0.1 $\mu$ F bypass as supply filtering. This does not eliminate the need for bypassing the supply nodes of the APA0712. The selection of bypass capacitors, especially  $C_b$ , is thus dependent upon desired PSRR requirements, click and pop performance.

To avoid start-up pop noise occurring, the bypass voltage should rise slower than the input bias voltage and the relationship shown in equation (4) should be maintained

$$C_b \frac{V_B}{65\mu A} + 50mS > 2\pi (R_i + R_f) C_i \quad (4)$$

The bypass capacitor is fed from an 80k $\Omega$  resistor inside the amplifier. Bypass capacitor,  $C_b$ , values of 1 $\mu$ F to 2.2 $\mu$ F ceramic or tantalum low-ESR capacitors are recommended for the best THD+N and noise performance. The bypass capacitance also affects the start up time. It is determined in the following equation

$$T_{start\ up} = C_b \frac{V_B}{65\mu A} + 50mS \quad (5)$$

### Power Supply Decoupling, $C_s$

The APA0712 is a high-performance CMOS audio

amplifier that requires adequate power supply decoupling to ensure the output total harmonic distortion (THD+N) is as low as possible. Power supply decoupling also prevents the oscillations caused by long lead length between the amplifier and the speaker.

The optimum decoupling is achieved by using two different type capacitors that target on different types of noise on the power supply leads. For higher frequency transients, spikes, or digital hash on the line, a good low equivalent-series-resistance (ESR) ceramic capacitor, typically 0.1 $\mu$ F placed as close as possible to the device  $V_{DD}$  lead works best. For filtering lower frequency noise signals, a large aluminum electrolytic capacitor of 10 $\mu$ F or greater placed near the audio power amplifier is recommended.

### Optimizing Depop Circuitry

Circuitry has been included in the APA0712 to minimize the amount of popping noise at power-up and when coming out of shutdown mode. Popping occurs whenever a voltage step is applied to the speaker. In order to eliminate clicks and pops, all capacitors must be fully discharged before turn-on.

Rapid on/off switching of the device or the shutdown function will cause the click and pop circuitry. The value of  $C_i$  will also affect turn-on pops (refer to Effective Bypass Capacitance). The bypass voltage rise up should be slower than input bias voltage. Although the bypass pin current source cannot be modified, the size of  $C_b$  can be changed to alter the device turn-on time and the amount of clicks and pops. By increasing the value of  $C_b$ , turn-on pop can be reduced. However, the tradeoff for using a larger bypass capacitor is to increase the turn-on time for this device. There is a linear relationship between the size of  $C_b$  and the turn-on time.

In the most cases, choosing a small value of  $C_i$  in the

## Application Descriptions (Cont.)

### Optimizing Depop Circuitry (Cont.)

range of 0.22µF to 0.47µF, C<sub>B</sub> being equal to 2.2µF should produce a virtually click-less and pop-less turn-on.

A high gain amplifier intensifies the problem as the small delta in voltage is multiplied by the gain. So it is advantageous to use low-gain configurations.

### Shutdown Function

In order to reduce power consumption while not in use, the APA0712 contains a shutdown function to externally turn off the amplifier bias circuitry. This shutdown feature turns the amplifier off when logic low is placed on the  $\overline{SD}$  pin for APA0712. The trigger point between a logic high and logic low level is typically 0.4V<sub>DD</sub>. It is best to switch between ground and the supply voltage V<sub>DD</sub> to provide maximum device performance. By switching the  $\overline{SD}$  pin to low level, the amplifier enters a low-consumption-current state, I<sub>DD</sub> for APA0712 is in shutdown mode. On normal operating, APA0712's  $\overline{SD}$  pin should pull to high level to keeping the IC out of the shutdown mode. The  $\overline{SD}$  pin should be tied to a definite voltage to avoid unwanted state changes.

### BTL Amplifier Efficiency

An easy-to-use equation to calculate efficiency starts out as being equal to the ratio of power from the power supply to the power delivered to the load. The following equations are the basis for calculating amplifier efficiency.

$$\text{Efficiency} = \frac{P_o}{P_{SUP}} \tag{6}$$

Where:

$$P_o = \frac{V_{O,RMS}^2}{R_L} = \frac{V_P^2}{2R_L} \tag{7}$$

$$V_{O,RMS} = \frac{V_P}{\sqrt{2}} \tag{8}$$

$$P_{SUP} = V_{DD} \times I_{DD,AVG} = V_{DD} \frac{2V_P}{\pi R_L} \tag{9}$$

Efficiency of a BTL configuration:

$$\frac{P_o}{P_{SUP}} = \frac{\frac{V_P^2}{2R_L}}{V_{DD} \times \frac{2V_P}{\pi R_L}} = \frac{\pi V_P}{4V_{DD}} \tag{10}$$

Table 1 employs equation 10 to calculate efficiencies for four different output power levels when load is 8Ω. The efficiency of the amplifier is quite low for lower power levels and rises sharply as power to the load is increased resulting in a near flat internal power dissipation over the normal operating range. Note that the internal dissipation at full output power is less than in the half power range. Calculating the efficiency for a specific system is the key to proper power supply design. For a mono 1.4W audio system with 8Ω loads and a 5V supply, the maximum draw on the power supply is almost 1.5W.

| Po (W) | Efficiency (%) | I <sub>DD</sub> (A) | V <sub>PP</sub> (V) | P <sub>D</sub> (W) |
|--------|----------------|---------------------|---------------------|--------------------|
| 0.2    | 28.34          | 0.14                | 1.79                | 0.55               |
| 0.5    | 44.94          | 0.22                | 2.83                | 0.55               |
| 0.7    | 53.12          | 0.26                | 3.35                | 0.50               |
| 1.0    | 63.59          | 0.32                | 4.00                | 0.35               |

**\*\*High peak voltages cause the THD+N to increase.**

Table 1. Efficiency Vs Output Power in 5-V/8Ω Differential Amplifier Systems

A final point to remember about linear amplifiers (either SE or BTL) is how to manipulate the terms in the efficiency equation to utmost advantage when possible. Note that in equation 10, V<sub>DD</sub> is in the denominator.

This indicates that as V<sub>DD</sub> goes down, efficiency goes up. In other words, use the efficiency analysis to choose the correct supply voltage and speaker impedance for the application.

### Power Dissipation

Whether the power amplifier is operated in BTL or SE modes, power dissipation is a major concern. In equa-

## Application Descriptions (Cont.)

### Power Dissipation (Cont.)

tion11 states the maximum power dissipation point for a SE mode operating at a given supply voltage and driving a specified load.

$$\text{SE mode: } P_{D,MAX} = \frac{V_{DD}^2}{2\pi^2 R_L} \quad (11)$$

In BTL mode operation, the output voltage swing is doubled as in SE mode. Thus the maximum power dissipation point for a BTL mode operating at the same given conditions is 4 times as in SE mode.

$$\text{BTL mode: } P_{D,MAX} = 2 \frac{V_{DD}^2}{\pi^2 R_L} \quad (12)$$

Even with this substantial increase in power dissipation, the APA0712 does not require extra heat-sink. The power dissipation from equation12, assuming a 5V-power supply and an 8Ω load, must not be greater than the power dissipation that results from the equation13:

$$P_{D,MAX} = \frac{T_{J,MAX} - T_A}{\theta_{JA}} \quad (13)$$

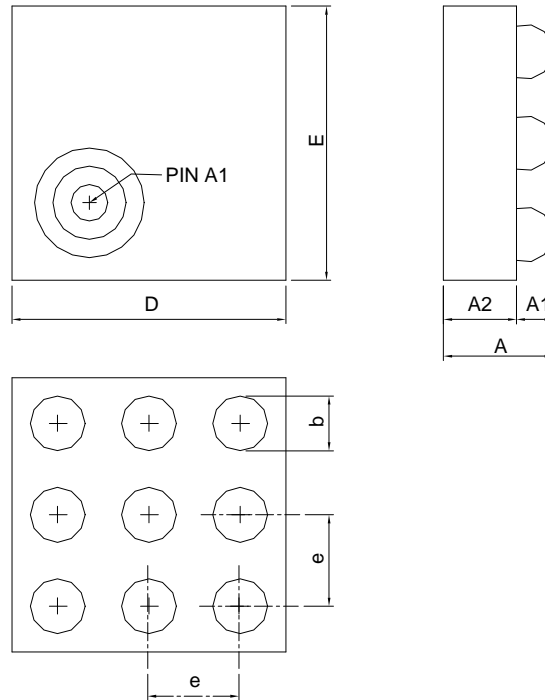
For WLCSP-9, the thermal resistance ( $\theta_{JA}$ ) is equal to 165°C/W.

Since the maximum junction temperature ( $T_{J,MAX}$ ) of APA0712 is 150°C and the ambient temperature ( $T_A$ ) is defined by the power system design, the maximum power dissipation, which the IC package is able to handle, can be obtained from equation13. Once the power dissipation is greater than the maximum limit ( $P_{D,MAX}$ ), the supply voltage ( $V_{DD}$ ) must be decreased, the load impedance ( $R_L$ ) must be increased or the ambient temperature should be reduced.



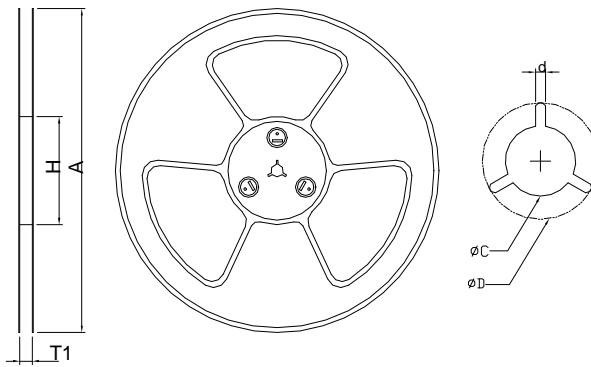
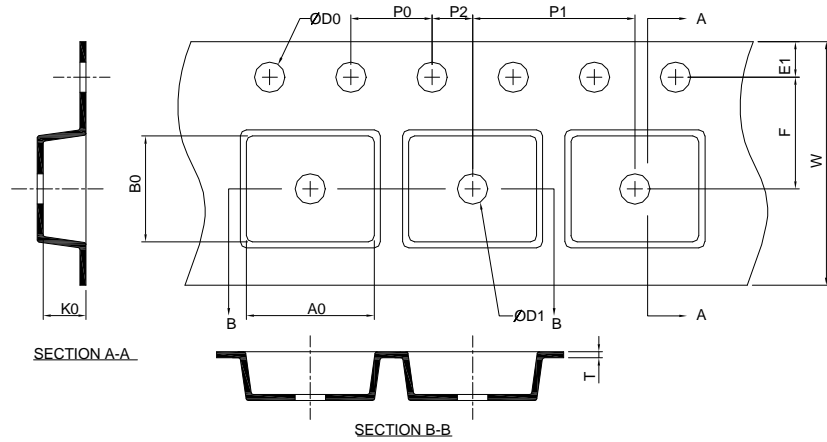
## Package Information

WLCSP - 9



| SYMBOL | WLCSP1.5x1.5-9 |      |           |       |
|--------|----------------|------|-----------|-------|
|        | MILLIMETERS    |      | INCHES    |       |
|        | MIN.           | MAX. | MIN.      | MAX.  |
| A      | 0.53           | 0.67 | 0.021     | 0.026 |
| A1     | 0.20           | 0.24 | 0.008     | 0.009 |
| A2     | 0.33           | 0.43 | 0.013     | 0.017 |
| b      | 0.29           | 0.31 | 0.011     | 0.012 |
| D      | 1.47           | 1.53 | 0.058     | 0.060 |
| E      | 1.47           | 1.53 | 0.058     | 0.060 |
| e      | 0.50 BSC       |      | 0.020 BSC |       |

### Carrier Tape & Reel Dimensions



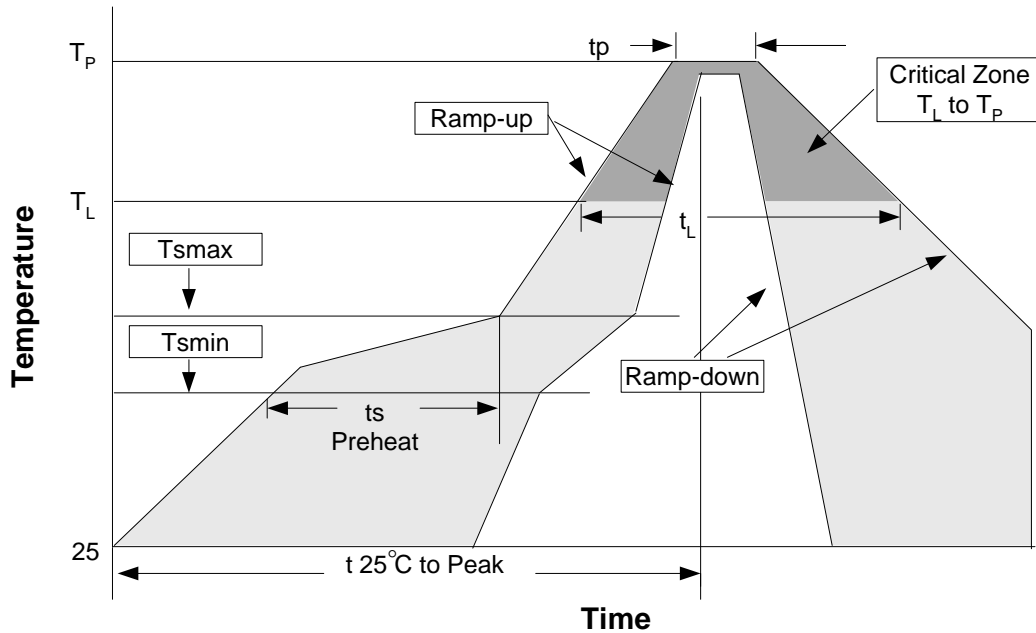
| Application          | A           | H          | T1                | C                  | d        | D                 | W          | E1         | F          |
|----------------------|-------------|------------|-------------------|--------------------|----------|-------------------|------------|------------|------------|
| WLCSP-9<br>(1.5*1.5) | 178.0 ±2.00 | 50 MIN.    | 8.4+2.00<br>-0.00 | 13.0+0.50<br>-0.20 | 1.5 MIN. | 20.2 MIN.         | 8.0 ±0.30  | 1.75 ±0.10 | 7.5 ±0.05  |
|                      | P0          | P1         | P2                | D0                 | D1       | T                 | A0         | B0         | K0         |
|                      | 4.0 ±0.10   | 12.0 ±0.10 | 2.0 ±0.10         | 1.5+0.10<br>-0.00  | 1.5 MIN. | 0.6+0.00<br>-0.40 | 1.70 ±0.10 | 1.70 ±0.10 | 0.90 ±0.10 |

(mm)

### Devices Per Unit

| Package Type | Unit        | Devices Per Reel |
|--------------|-------------|------------------|
| WLCSP-9      | Tape & Reel | 3000             |

**Reflow Condition (IR/Convection or VPR Reflow)**



**Reliability Test Program**

| Test item      | Method              | Description                   |
|----------------|---------------------|-------------------------------|
| SOLDERABILITY* | MIL-STD-883D-2003   | 245°C, 5 sec                  |
| HOLT           | MIL-STD-883D-1005.7 | 1000 Hrs Bias @125°C          |
| PCT            | JESD-22-B, A102     | 168 Hrs, 100%RH, 121°C        |
| TST            | MIL-STD-883D-1011.9 | -65°C~150°C, 200 Cycles       |
| ESD            | MIL-STD-883D-3015.7 | VHBM > 2KV, VMM > 200V        |
| Latch-Up       | JESD 78             | 10ms, 1 <sub>tr</sub> > 100mA |

\* Solderability test doesn't apply to "WLCSP-9".

**Classification Reflow Profiles**

| Profile Feature  | Sn-Pb Eutectic Assembly | Pb-Free Assembly |
|--|-------------------------|------------------|
| Average ramp-up rate (T <sub>L</sub> to T <sub>P</sub> )     | 3°C/second max.         | 3°C/second max.  |
| Preheat  |                         |                  |
| - Temperature Min (T <sub>smin</sub> )                       | 100°C                   | 150°C            |
| - Temperature Max (T <sub>smax</sub> )                       | 150°C                   | 200°C            |
| - Time (min to max) (t <sub>s</sub> )                        | 60-120 seconds          | 60-180 seconds   |
| Time maintained above:                                       |                         |                  |
| - Temperature (T <sub>L</sub> )                              | 183°C                   | 217°C            |
| - Time (t <sub>L</sub> )                                     | 60-150 seconds          | 60-150 seconds   |
| Peak/Classification Temperature (T <sub>P</sub> )            | See table 1             | See table 2      |
| Time within 5°C of actual Peak Temperature (t <sub>p</sub> ) | 10-30 seconds           | 20-40 seconds    |
| Ramp-down Rate   | 6°C/second max.         | 6°C/second max.  |
| Time 25°C to Peak Temperature                                | 6 minutes max.          | 8 minutes max.   |

Notes: All temperatures refer to topside of the package. Measured on the body surface.

**Classification Reflow Profiles (Cont.)**

Table 1. SnPb Eutectic Process – Package Peak Reflow Temperatures

| Package Thickness | Volume mm <sup>3</sup><br><350 | Volume mm <sup>3</sup><br>≥350 |
|-------------------|--------------------------------|--------------------------------|
| <2.5 mm           | 240 +0/-5°C                    | 225 +0/-5°C                    |
| ≥2.5 mm           | 225 +0/-5°C                    | 225 +0/-5°C                    |

Table 2. Pb-free Process – Package Classification Reflow Temperatures

| Package Thickness | Volume mm <sup>3</sup><br><350 | Volume mm <sup>3</sup><br>350-2000 | Volume mm <sup>3</sup><br>>2000 |
|-------------------|--------------------------------|------------------------------------|---------------------------------|
| <1.6 mm           | 260 +0°C*                      | 260 +0°C*                          | 260 +0°C*                       |
| 1.6 mm – 2.5 mm   | 260 +0°C*                      | 250 +0°C*                          | 245 +0°C*                       |
| ≥2.5 mm           | 250 +0°C*                      | 245 +0°C*                          | 245 +0°C*                       |

\* Tolerance: The device manufacturer/supplier **shall** assure process compatibility up to and including the stated classification temperature (this means Peak reflow temperature +0°C. For example 260°C+0°C) at the rated MSL level.

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